QUIZ-01

Date: 14-02-2025

INTEGRATED ELECTRONICS

ECE 214

Time 1 Hr. 20 Min.

Max. Marks 20

(All plagiarism policy of IIIT Delhi is applicable)

1. For each of the cases mentioned in Table I and Table II find weather the transistor is in active, saturation and cut off mode? (All values are in volts)

Table I for NPN

Case	V_{B}	V_{E}	V_{C}	
1.	0.7	0	0.7	1
2.	0.8	0	0.1	5
3.	0	-0.7	-0.6	S
4.	-2.0	-2.7	0	A

Table II for PNP

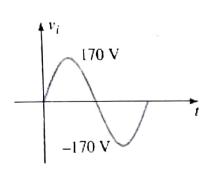
Case	V_{B}	VE	V_{C}	
1.	-0.68	0	-0.68	A
2.	-0.78	0	-0.1	9
3.	0	0.68	0.56	K
(4)	3.18	2.58	0	C

(4 Marks, CO1, CO2)

2. (a) A npn transistor having a reverse saturation current $I_{CBO} = 10\mu A$ is operated in CE mode. If the base current is 250 μA . Calculate I_C and I_E , assume that $\alpha = 0.98$.

(2 Marks, CO2)

(b) Determine the output waveform for the network of Fig. 1 and calculate the average and rms voltage level. (Assuming all diodes are ideal)



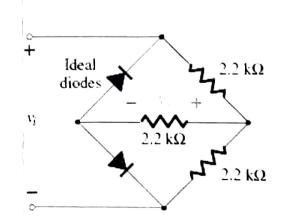
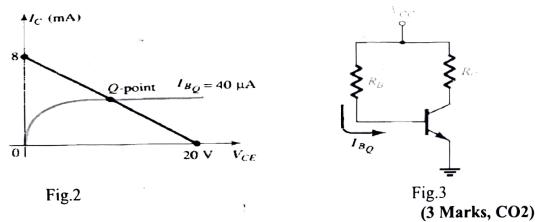
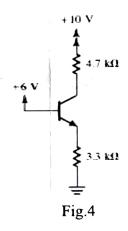


Fig.1

Given the device characteristics of Fig.2 and Fig.3 for the fixed-bias configuration, considering V_{BE} =0.7 V determine V_{CC} , R_B and R_C



From Fig. 4 determine the voltages at all nodes and the currents through all branches. Assume that the transistor β is specified to be at least 50. Considering $V_{BE} = 0.7 \text{ V}$ and also check the BJT is in active mode, if not in active mode, then assume given transistor is in deep saturation mode. Also calculate β forced if required.



(5 Marks, CO2)

 \sim 5 Find the values of I and V in the circuits shown in Fig. 5 assume all diodes are ideal.

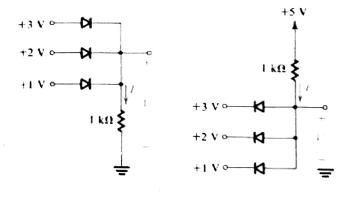


Fig.5

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- 1. For the circuit shown below in fig.1 & fig.2.
 - Calculate the o/p voltages V_{01} and V_{02} in fig.1(a) and fig.1(b) for V_m = 4.2V, 5V,5.7V, 10V theoretically.
 - b) When o/p voltage of fig1(a) feeds to input of fig1(b), the cascaded circuit is achieved, shown in fig.2.then calculate o/p voltage of cascaded circuit V_{02} for V_m = 4.2V, 5V ,5.7V, 10V theoretically.
 - c) Sketch the o/p voltage waveform of the cascaded circuit given in fig.2 for V_m =4.2, 5V,5.7V, 10V on LTspice.

Assuming Zener diode as ideal and forward bias voltage drop of normal diode to be 0.7V (Assume $V_i=V_m \sin \omega t$).

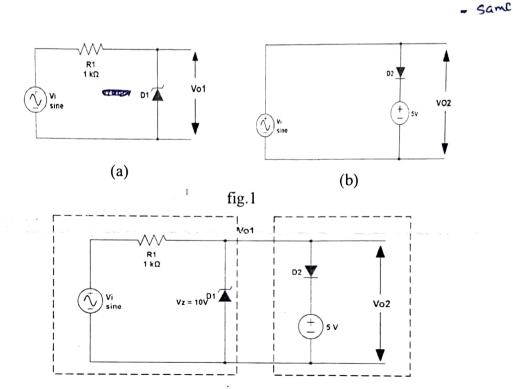


fig.2

MAD

Simulation Tutorial 02

- 1. In the BJT amplifier circuit shown below in Fig.1. Assume V_{BE} is 0.7 V. The collector voltage Vc is given as 5V.
 - (a) Draw the Thevenin equivalent of the given circuit and calculate the value of resistance R₂ theoretically, when β is 100. [3 Marks, CO2]
 - (b) Calculate the Q point for $\beta_1 = 100$ and $\beta_2 = 150$. (Put R₂ obtained from part(a)) [2 Marks, CO2]
 - (c) Show the operating points and plot the $I_c v/s V_{CE}$ characteristics of Thevenin equivalent circuit when $\beta_1 = 100$ and $\beta_2 = 150$ using LTspice. [5 Marks, CO2]

Note: Use transistor 2N2222, NXP, NPN from the library and edit β_1 , and β_2 values according to the question.

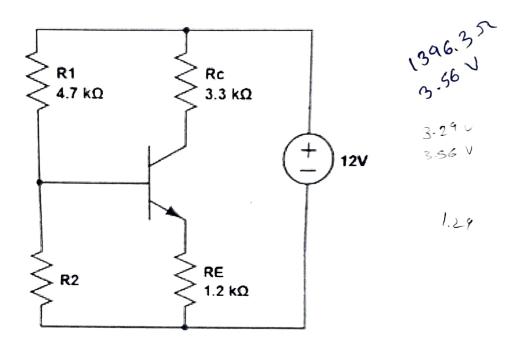


Fig.1